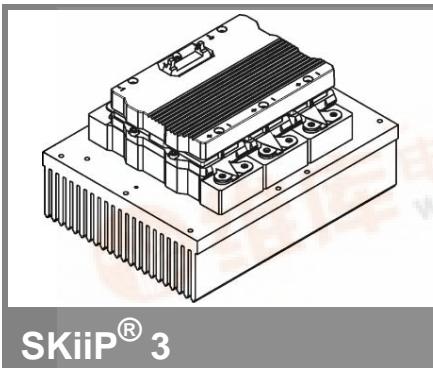


SKIIP 513GD122-3DUL



6-pack-integrated intelligent Power System

Power section

SKIIP 513GD122-3DUL

Preliminary Data

Features

- SKIIP technology inside
- SPT (Soft Punch Through) IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKIIP® 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532

¹⁾ with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

| Absolute Maximum Ratings | | $T_s = 25^\circ\text{C}$ unless otherwise specified | | |
|--------------------------------|---|---|--|-------------------|
| Symbol | Conditions | Values | | Units |
| IGBT | | | | |
| V_{CES} | | 1200 | | V |
| V_{CC} ¹⁾ | Operating DC link voltage | 900 | | V |
| V_{GES} | | ± 20 | | V |
| I_C | $T_s = 25 \text{ (70) }^\circ\text{C}$ | 500 (375) | | A |
| Inverse diode | | | | |
| $I_F = -I_C$ | $T_s = 25 \text{ (70) }^\circ\text{C}$ | 440 (340) | | A |
| I_{FSM} | $T_j = 150^\circ\text{C}$, $t_p = 10 \text{ ms}$; sin | 3500 | | A |
| $I_{\text{ft}}^{\text{Diode}}$ | Diode, $T_j = 150^\circ\text{C}$, 10 ms | 61 | | kA ² s |
| T_j (T_{stg}) | | - 40 ... + 150 (125) | | °C |
| V_{isol} | rms, AC, 1 min, main terminals to heat sink | 3000 | | V |
| $I_{\text{AC-terminal}}$ | per AC terminal, rms, $T_s = 70^\circ\text{C}$, | 400 | | A |
| | $T_{\text{terminal}} < 115^\circ\text{C}$ | | | |

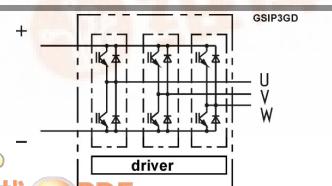
| Characteristics | | $T_s = 25^\circ\text{C}$ unless otherwise specified | | |
|----------------------|--|---|-----------|------|
| Symbol | Conditions | min. | typ. | max. |
| IGBT | | | | |
| V_{CEsat} | $I_C = 300 \text{ A}$, $T_j = 25 \text{ (125) }^\circ\text{C}$; measured at terminal | 2,3 (2,5) | 2,6 | V |
| V_{CEO} | $T_j = 25 \text{ (125) }^\circ\text{C}$; at terminal | 1,1 (1) | 1,3 (1,2) | V |
| r_{CE} | $T_j = 25 \text{ (125) }^\circ\text{C}$; at terminal | 3,8 (5) | 4,5 (5,6) | mΩ |
| I_{CES} | $V_{GE} = 0 \text{ V}$, $V_{CE} = V_{CES}$, $T_j = 25 \text{ (125) }^\circ\text{C}$ | 1,2 (36) | | mA |
| $E_{on} + E_{off}$ | $I_C = 300 \text{ A}$, $V_{CC} = 600 \text{ V}$ | 90 | | mJ |
| | $T_j = 125^\circ\text{C}$, $V_{CC} = 900 \text{ V}$ | 159 | | mJ |
| $R_{CC+EE'}$ | terminal chip, $T_j = 25^\circ\text{C}$ | 0,5 | | mΩ |
| L_{CE} | top, bottom | 12 | | nH |
| C_{CHC} | per phase, AC-side | 1,7 | | nF |
| Inverse diode | | | | |
| $V_F = V_{EC}$ | $I_F = 300 \text{ A}$, $T_j = 25 \text{ (125) }^\circ\text{C}$; measured at terminal | 1,8 (1,5) | 2,3 | V |
| V_{TO} | $T_j = 25 \text{ (125) }^\circ\text{C}$ | 1 (0,7) | 1,2 (0,9) | V |
| r_T | $T_j = 25 \text{ (125) }^\circ\text{C}$ | 2,6 (2,8) | 3,5 (3,7) | mΩ |
| E_{rr} | $I_C = 300 \text{ A}$, $V_{CC} = 600 \text{ V}$ | 24 | | mJ |
| | $T_j = 125^\circ\text{C}$, $V_{CC} = 900 \text{ V}$ | 31 | | mJ |

| Mechanical data | | | | |
|-----------------|-------------------------------|-----|----|----|
| M_{dc} | DC terminals, SI Units | 6 | 8 | Nm |
| M_{ac} | AC terminals, SI Units | 13 | 15 | Nm |
| w | SKIIP® 3 System w/o heat sink | 2,4 | | kg |
| w | heat sink | 7,5 | | kg |

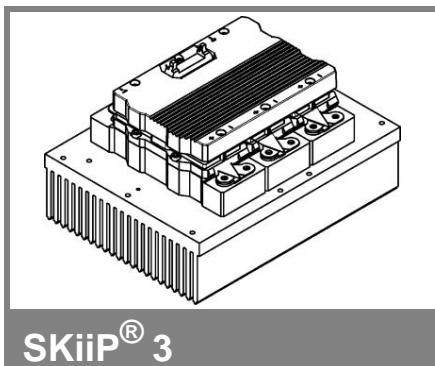
Thermal characteristics (PX16 heat sink with fan SKF16B-230-1); "s" reference to heat sink; "r" reference to built-in temperature sensor (acc.IEC 60747-15)

| $R_{th(j-s)l}$ | per IGBT | | 0,059 | K/W |
|----------------|------------------------------------|-----|-----------------------------|------|
| $R_{th(j-s)D}$ | per diode | | 0,115 | K/W |
| Z_{th} | $R_i \text{ (mK/W) (max. values)}$ | | $\tau_{\text{a}}(\text{s})$ | |
| 1 | 2 | 3 | 4 | 1 |
| 10,2 | 28,8 | 21 | 0 | 363 |
| 36 | 36 | 54 | 60 | 30 |
| 2,1 | 20 | 5,5 | 1,4 | 210 |
| | | | | 0,18 |
| | | | | 5 |
| | | | | 0,04 |
| | | | | 0,25 |
| | | | | 0,04 |
| | | | | 11 |
| | | | | 0,4 |

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SKiiP 513GD122-3DUL



6-pack-integrated intelligent Power System

6-pack
integrated gate driver
SKiiP 513GD122-3DUL

Preliminary Data

Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformer
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

| Absolute Maximum Ratings | | $T_a = 25^\circ\text{C}$ unless otherwise specified | |
|----------------------------------|---|---|-------------------------|
| Symbol | Conditions | Values | Units |
| V_{S2} | unstabilized 24 V power supply | 30 | V |
| V_i | input signal voltage (high) | 15 + 0,3 | V |
| dv/dt | secondary to primary side | 75 | $\text{kV}/\mu\text{s}$ |
| V_{isolIO} | input / output (AC, rms, 2 s) | 3000 | V |
| V_{isolPD} | partial discharge extinction voltage, rms, $Q_{\text{PD}} \leq 10 \text{ pC}$ | 1170 | V |
| V_{isol12} | output 1 / output 2 (AC, rms, 2 s) | 1500 | V |
| f_{sw} | switching frequency | 15 | kHz |
| f_{out} | output frequency for $I=I_c$; sin. | 1 | kHz |
| $T_{\text{op}} (T_{\text{stg}})$ | operating / storage temperature | - 40 ... + 85 | $^\circ\text{C}$ |

| Characteristics $(T_a = 25^\circ\text{C})$ | | | | | |
|--|--|--|------|------|------------------|
| Symbol | Conditions | min. | typ. | max. | Units |
| V_{S2} | supply voltage non stabilized | 13 | 24 | 30 | V |
| I_{S2} | $V_{S2} = 24 \text{ V}$ | $365+30*f/\text{kHz}+0,00111*(I_{AC}/A)^2$ | | | mA |
| V_{iT+} | input threshold voltage (High) | 12,3 | | | V |
| V_{iT-} | input threshold voltage (Low) | 4,6 | | | V |
| R_{IN} | input resistance | 10 | | | $\text{k}\Omega$ |
| C_{IN} | input capacitance | 1 | | | nF |
| $t_{d(on)}^{\text{IO}}$ | input-output turn-on propagation time | 1,3 | | | μs |
| $t_{d(off)}^{\text{IO}}$ | input-output turn-off propagation time | 1,3 | | | μs |
| $t_{\text{pERRRESET}}$ | error memory reset time | 9 | | | μs |
| t_{TD} | top / bottom switch interlock time | 3,3 | | | μs |
| $I_{\text{analogOUT}}$ | max. 5 mA; 8 V corresponds to 15 V supply voltage for external components | 500 | | | A |
| I_{s1out} | max. load current | 50 | | | mA |
| I_{TRIPSC} | over current trip level ($I_{\text{analog OUT}} = 10 \text{ V}$) | 625 | | | A |
| T_{tp} | over temperature protection | 110 | 120 | | $^\circ\text{C}$ |
| U_{DCTRIP} | $U_{\text{DC}}\text{-protection}$ ($U_{\text{analog OUT}} = 9 \text{ V}$); (option for GB types) | 900 | | | V |

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